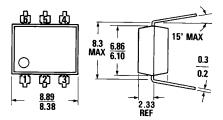
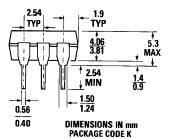


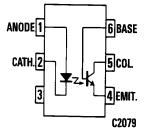
TIL111

PACKAGE DIMENSIONS





ST1603A



DESCRIPTION

The TIL111 is a phototransistor-type optically coupled isolator. An infrared emitting diode manufactured from specially grown gallium arsenide is selectively coupled with an NPN silicon phototransistor. The device is supplied in a standard plastic six-pin dual-in-line package.

FEATURES

■ Underwriters Laboratory (UL) recognized File #E90700

APPLICATIONS

- Power supply regulators
- Digital logic inputs
- Microprocessor inputs
- Appliance sensor systems
- Industrial controls

ABSOLUTE MAXIMUM RATINGS (T _x =25	C Unless Otherwise Specified)
TOTAL PACKAGE Storage temperature	INPUT DIODE Forward DC current 100 mA Reverse voltage 3 V Peak forward current (1 μs pulse, 300 pps) 3.0 A Power dissipation 25°C ambient 150 mW Derate linearly from 25°C 2 mW/°C
Derate linearly from 25°C 3.3 mW/°C	OUTPUT TRANSISTOR Power dissipation at 25°C 150 mW Derate linearly from 25°C 2 mW/°C V _{CEO} 30 V V _{CBO} 70 V V _{ECO} 7 V Collector current (continuous) 100 mA



ELECTRICAL CHARACTERISTICS (At 25°C Free-Air Temperature)

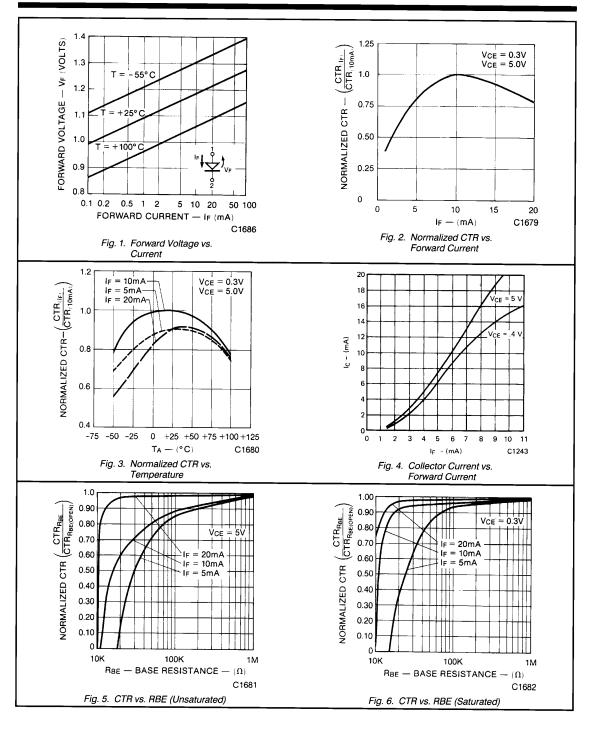
INDIVIDUAL COMPONENT CHARACTERISTICS						
PARAMETER	SYMBOL	TIL111			UNIT	TEST CONDITIONS
		MIN.	TYP.	MAX.		TEST CONDITIONS
INPUT DIODE Input diode static reverse current	I _R			10	μΑ	V _R =3 V
Input diode static forward voltage	V _F	-	1.2	1.4	٧	I _F =16 mA
OUTPUT TRANSISTOR Collector-base breakdown voltage	V _{(BR)CBO}	70			٧	$I_c=10 \mu A, I_E=0, I_F=0$
Collector-emitter breakdown voltage	V _{(BR)CEO}	30			٧	I _c =1 mA, I _B =0, I _F =0
Emitter-base breakdown voltage	V _{(BR)EBO}	7			٧	$I_{E}=10 \mu A, I_{C}=0, I_{F}=0$
Transistor static forward current transfer ratio	h _{FE}	100	300			$V_{CE} = 5 \text{ V}, I_{C} = 10 \text{ mA}, I_{F} = 0$

	PARAMETER	SYMBOL	TIL111			UNIT	TEST CONDITIONS
			MIN.	TYP.	MAX.	0.00	TEST CONDITIONS
On-state	Phototransistor operation	I _{C(on)}	2	7		mA	$V_{CE} = 0.4 \text{ V}, I_F = 16 \text{ mA}, I_B = 0$
collector current	Photodiode operation	I _{C(on)}	7	20		μΑ	$V_{CB} = 0.4 \text{ V}, I_F = 16 \text{ mA}, I_E = 0$
Off-state collector current	Phototransistor			1	50		V _{CE} =10 V, I _E =0, I _B =0
	operation	$I_{C(off)}$		•	00	nA	V (1
	Photodiode	I _{C(off)}		0.1	20	101	V _{CR} =10 V, I _E =0, I _E =0
	operation	•C(on)		0.1	20		• CB — 10 •, It — 0, IE — 0
Collector-er saturation		$V_{\text{CE(sat)}}$		0.25	0.4	٧	I _c =2 mA, I _F =16 mA, I _B =0

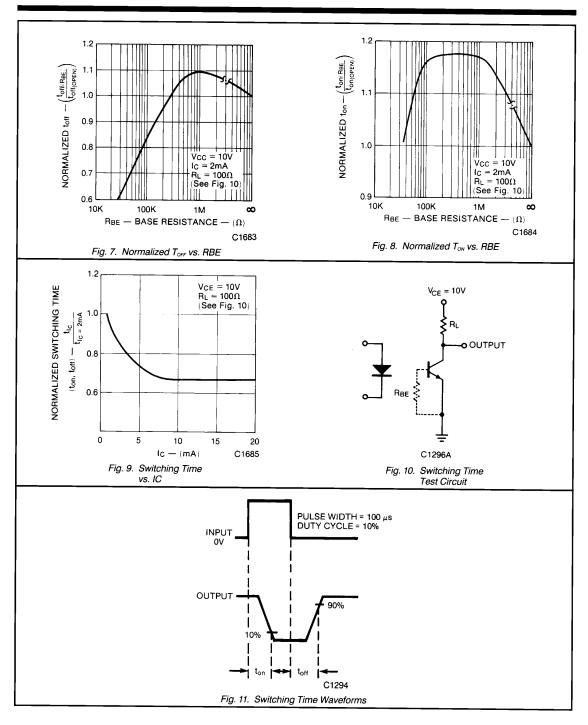
PARAMETER	SYMBOL	TIL111			UNIT	TEST CONDITIONS	
	- AIAMEISA	J.MBOL	MIN.	TYP.	MAX.	ONII	TEST CONDITIONS
Rise time	Phototransistor operation	t,		5	10	μS	V_{cc} =10 V, $I_{C(on)}$ =2 mA, R_L - 100 Ω
Fall time		t _f	_	J	.5	μο	
Rise time	Photodiode operation	t,		4	5		V _{cc} =10 V, I _{c(on)} =20 μA, R ₁ - 1 kΩ
Fall time		t,	-	'		μS	V _{CC} -10 V, I _{C(on)} -20 μA, H _L -1 K22

ISOLATION CHARACTERISTICS							
PARAMETER	SYMBOL	TIL111			UNIT	TEST CONDITIONS	
		MIN.	TYP.	MAX.	ONII	1231 CONDITIONS	
Input-to-output internal resistance	r _{io}	1011			Ω	$V_{ISO} = \pm 1.5 \text{ kV}$	
Input-to-output capacitance	C _{io}		1	1.3	pF	V _{in-out} =0, f=1 MHz, See Note 6	
Isolation voltage	V _{iso}	7500 5300			VAC-PEAK VAC-RMS	$I_{I:O} \le 1 \mu A$, 1 minute $I_{I:O} \le 1 \mu A$, 1 minute	











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